MIL 39006/22

MIL Qualified - CLR79



Wet tantalum capacitors
Hermetically sealed tantalum cases
High ripple current

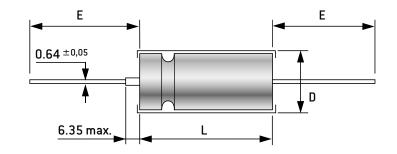
Axial leads Polarized

ELECTRICAL AND CLIMATIC CHARACTERISTICS

	MIL 39006/22
Datail an acidination	MIL-PRF-39006/22
Detail specification	Failure rate level M & Failure rate level P
Operating temperature	−55°C+125°C
Capacitance range	1,7μF ⇒ 1200μF
Tolerance	±10% - ±20%
Voltage range	6V ⇔ 125V
Max. capacitance change –55°C	see table
Max. capacitance change +85°C	see table
Max. capacitance change +125°C	see table
Maximum DF at +25°C	see table
Max. impedance at 120Hz –55°C	see table
Max. leakage current at +25°C	see table
Max. leakage current at +85°C / +125°C	see table
Max. ripple current at 40kHz +85°C	see table
Max. Reverse voltage at +85°C	3 volts
Max. Reverse voltage at +125°C	2 volts
Max. surge voltage at +85°C	1,15 x U _R

DIMENSIONS (mm)

Case code	With insulatin		With insulating sleeve	Lead length
case code	D±0,41	L +0,79 L -0,41	D max.	E ±6,35
T1	4,78	11,51	5,56	38,10
T2	7,14	16,28	7,92	57,15
T3	9,52	19,46	10,31	57,15
T4	9,52	26,97	10,31	57,15



PACKAGING, CONSTRUCTION:

see general characteristics

HOW TO ORDER

EXXELIA PN	Model code	Dash Number	Vibration and shock (optional)
EAALLIATI	M39006/22	-0220	Н
			-= Without

MIL Qualified - CLR79

MIL 39006/22

STANDARD RATINGS - ELECTRICAL CHARACTERISTICS

	Case	Dash Number Failure Rate Level M		Dash Number Failure Rate Level P		Capacita	Capacitance maximum change			Max. Imped-	Max.	l leak	Irms Max. 40kHz	Max. ESR
	(code)	±10%	±20%	±10%	±20%	−55°C (%)	+85°C (%)	+125°C (%)	Max. DF +25°C (%)	ance 120Hz -55°C (Ω)	+25°C (µA)	+85°C +125°C (µA)	+85°C (mA)	120Hz +25°C (Ω)
					Rated v	voltage (+8	5°C) 6 V - De	rated voltag	, ge (+125°C) .	4 V				
30	T1	0002	0001	0222	0221	-40	+10,5	+12	9	100	1	2	820	3,98
68	T1	0005	0004	0225	0224	-40	+14	+16	15	60	1	2	960	3,16
140	T2	0008	0007	0228	0227	-40	+14	+16	21	40	1	3	1200	1,99
270	T2	0011	0010	0231	0230	-44	+17,5	+20	45	25	1	6,5	1375	2,21
330	T3	0014	0013	0234	0233	-44	+14	+16	36	20	2	7,9	1800	1,45
560	T3	0017	0016	0237	0236	-64	+17,5	+20	55	25	2	13	1900	1,30
1200	T4	0020	0019	0240	0239	-80	+25	+25	90	20	3	14	2265	1,00
					Rated	voltage (+8	5°C) 8 V - De	rated voltag	ge (+125°C)	5 V				
25	T1	0022	0021	0242	0241	-40	+10,5	+12	7,5	100	1	2	820	3,98
56	T1	0025	0024	0245	0244	-40	+14	+16	14	59	1	2	900	3,32
120	T2	0028	0027	0248	0247	-44	+17,5	+20	20	50	1	2	1220	2,21
220	T2	0031	0030	0251	0250	-44	+17,5	+20	37	30	1	7	1370	2,23
290	T3	0034	0033	0254	0253	-64	+17,5	+20	34	25	2	6	1770	1,56
430	T3	0037	0036	0257	0256	-64	+17,5	+20	46	25	2	14	1825	1,42
850	T4	0040	0039	0260	0259	-80	+25	+25	60	22	4	16	2330	0,94
					Rated v	oltage (+85	°C) 10 V - De	rated volta	ge (+125°C)	7 V				
20	T1	0042	0041	0262	0261	-32	+10,5	+12	6	175	1	2	820	3,98
47	T1	0045	0044	0265	0264	-36	+14	+16	13	100	1	2	855	3,67
100	T2	0048	0047	0268	0267	-36	+14	+16	15	60	1	4	1200	1,99
180	T2	0051	0050	0271	0270	-36	+14	+16	30	40	1	7	1365	2,21
250	T3	0054	0053	0274	0273	-40	+14	+16	30	30	2	10	1720	1,59
390	T3	0057	0056	0277	0276	-64	+17,5	+20	44	25	2	16	1800	1,50
750	T4	0060	0059	0280	0279	-80	+25	+25	50	23	4	16	2360	0,88
						nitage (+85			ge (+125°C)					-,
15	T1	0062	0061	0282	0281	-24	+10,5	+12	5	155	1	2	780	4,42
33	T1	0065	0064	0285	0284	-28	+10,5	+16	10	90	1	2	820	4,02
70	T2	0068	0067	0288	0287	-28	+14	+16	13		1	4	1150	2,46
120	T2	0071	0070	0291	0290	-28	+17,5	+20	18	50	1	7	1450	1,99
170	T3	0074	0073	0294	0293	-32	+14	+16	25	35	2	10	1480	1,95
270	T3	0077	0076	0297	0296	-56	+17,5	+20	32	30	2	16	1740	1,57
540	T3	0080	0079	0300	0299	-80	+25	+25	40	23	6	24	2330	0,98
540	14	0000	0079	0300							0	24	2330	0,96
						_ ` `			ge (+125°C)			_		
10	T1	0082	0081	0302	0301	-16	+8	+9	4	220	1	2	715	5,31
22	T1	0085	0084	0305	0304	-20	+10,5	+12	6,6	140	1	2	825	3,98
50	T2	0088	0087	0308	0307	-28	+13	+15	11	70	1	2	1130	2,92
100	T2	0091	0090	0311	0310	-28	+13	+15	15	50	1	10	1435	1,99
120	T3	0094	0093	0314	0313	-32	+13	+15	21	38	2	6	1450	2,32
180	T3	0097	0096	0317	0316	-48	+13	+15	26	32	2	18	1525	1,92
350	T4	0100	0099	0320	0319	-70	+25	+25	35	24	7	28	1970	1,33
									ge (+125°C)					
8	T1	0102	0101	0322	0321	-16	+8	+12	4	275	1	2	640	6,64
15	T1	0105	0104	0325	0324	-20	+10,5	+12	5	175	1	2	780	4,42
40	T2	0108	0107	0328	0327	-24	+10,5	+12	10	65	1	5	1120	3,32
68	T2	0111	0110	0331	0330	-24	+13	+15	13	60	1	8	1285	2,54
100	T3	0114	0113	0334	0333	-28	+10,5	+12	17	40	2	12	1450	2,26
150	T3	0117	0116	0337	0336	-48	+13	+15	23	35	2	18	1525	2,03
300	T4	0120	0119	0340	0339	-60	+25	+25	31	25	8	32	1950	1,37



MIL 39006/22

MIL Qualified - CLR79

STANDARD RATINGS - ELECTRICAL CHARACTERISTICS

Capacitance		Dash Numl	ber Level M	Dash Number Level P		Capacita	nce maximu	m change	May DE	Max. Impedance-	Max.	lleak	Irms Max.	
120Hz +25°C (μF)	Case (code)	±10%	±20%	± 10%	±20%	−55°C (%)	+85°C (%)	+125°C (%)	Max. DF +25℃ (%)	120 Hz −55°C (Ω)	+25°C (µA)	+85℃ +125℃ (µA)	40kHz +85°C (mA)	120Hz +25°C (Ω)
					Rated vo	oltage (+85°	C) 50 V - De	rated voltag	e (+125°C)	30 V				
5	T1	0122	0121	0342	0341	-16	+5	+6	3	400	1	2	580	7,96
10	T1	0125	0124	0345	0344	-24	+8	+9	4	250	1	2	715	5,31
25	T2	0128	0127	0348	0347	-20	+10,5	+12	8	95	1	5	1005	4,25
47	T2	0131	0130	0351	0350	-28	+13	+15	11	70	1	9	1155	3,11
60	T3	0134	0133	0354	0353	-16	+10,5	+12	12	45	2	12	1335	2,65
82	T3	0137	0136	0357	0356	-32	+13	+15	15	45	2	16	1400	2,43
160	T4	0140	0139	0360	0359	-50	+25	+25	17	27	8	32	1900	1,41
					Rated vo	ltage (+85°	C) 60 V - De	rated voltag	ge (+125°C)	40 V				
4	T1	0142	0141	0362	0361	-16	+5	+6	2,8	550	1	2	525	9,29
8,2	T1	0145	0144	0365	0364	-24	+8	+9	4	275	1	2	625	6,47
20	T2	0148	0147	0368	0367	-16	+10,5	+12	7	105	1	5	930	4,64
39	T2	0151	0150	0371	0370	-28	+10,5	+12	10	90	1	9	1110	3,40
50	T3	0154	0153	0374	0373	-16	+10,5	+12	10	50	2	12	1330	2,65
68	T3	0157	0156	0377	0376	-32	+10,5	+12	13	50	2	16	1365	2,54
140	T4	0160	0159	0380	0379	-40	+20	+20	16	28	8	32	1850	1,52
					Rated vo	ltage (+85°	°C) 75 V - De	rated voltag	ge (+125°C)	50 V				
3,5	T1	0162	0161	0382	0381	-16	+5	+6	2,5	650	1	2	525	9,48
6,8	T1	0165	0164	0385	0384	-20	+8	+9	3,5	300	1	2	610	6,83
15	T2	0168	0167	0388	0387	-16	+8	+9	6	150	1	5	890	5,31
33	T2	0171	0170	0391	0390	-24	+10,5	+15	10	90	1	10	1000	4,02
40	T3	0174	0173	0394	0393	-16	+10,5	+12	9	60	2	12	1250	2,99
56	T3	0177	0176	0397	0396	-28	+10,5	+15	11	60	2	17	1335	2,61
110	T4	0180	0179	0400	0399	-35	+20	+20	12	29	9	36	1850	1,45
					Rated vo	 tage	C) 100 V - De	rated volta	ge (+125°C	65 V				
2,5	T1	0182	0181	0402	0401	-16	+7	+8	2	950	1	2	505	10,62
4,7	T1	0185	0184	0405	0404	-16	+7	+8	3	500	1	2	565	8,47
11	T2	0188	0187	0408	0407	-16	+8	+8	5	200	1	4	835	6,03
22	T2	0191	0190	0411	0410	-16	+8	+8	7,5	100	1	9	965	4,52
30	T3	0194	0193	0414	0413	-16	+8	+8	7	80	2	12	1240	3,10
43	T3	0197	0196	0417	0416	-20	+8	+8	8,5	70	2	17	1335	2,62
86	T4	0200	0199	0420	0419	-25	+15	+15	10	30	9	36	1800	1,54
					Rated vo	 tage [+85°	C) 125 V - De	rated volta	ge [+125°C]	85 V				
1,7	T1	0202	0201	0422	0421	-16	+7	+8	2	1250	1	2	415	15,61
3,6	T1	0205	0204	0425	0424	-16	+7	+8	2,7	600	1	2	520	9,95
9	T2	0208	0207	0428	0427	-16	+7	+8	5	240	1	5	755	7,37
14	T2	0211	0210	0431	0430	-16	+7	+8	6	167	1	7	860	5,69
18	T3	0214	0213	0434	0433	-16	+7	+8	5	129	2	9	1130	3,69
25	T3	0217	0216	0437	0436	-16	+7	+8	6	93	2	13	1200	3,18
56	T4	0220	0219	0440	0439	-25	+15	+15	6,5	32	10	40	1800	1,54



CAPACITANCE

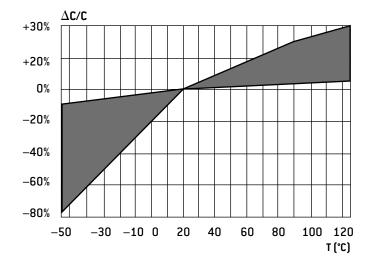
The capacitance is defined by a rated value (C_R , indicated on the capacitor) and a tolerance (generally $\pm 20\%$).

The capacitance is measured at a 100Hz or at a 120Hz frequency under a 0,1 to 1 V_{AC} voltage and a 2,1 to 2,5 V bias (or 9 to 10 V for $U_R \ge 100$ V).

At room temperature, it must be in the range defined by the rated value and the tolerance.

Capacitance change vs temperature: see typical curves below. Maximum changes are given, for each type, on the data sheets.

CAPACITANCE CHANGE VS TEMPERATURE



TOLERANCE (ON RATED CAPACITANCE)

It defines, with the rated capacitance, the range in which the capacitance value must be at room temperature.

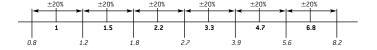
e.g.: Rated capacitance: 100µF

Tolerance: 20%

The measured capacitance must be between:

 $100 - (20\% \text{ of } 100) = 80\mu\text{F} \text{ and } 100 + (20\% \text{ of } 100) = 120\mu\text{F}$

The standard tolerance for tantalum capacitors is 20%.

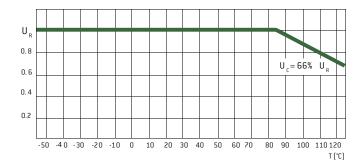




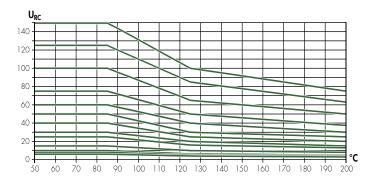
DIRECT DC VOLTAGE

The rated voltage $\{U_R\}$, indicated on the capacitor, is the maximum DC voltage which can be applied continuously between -55° C and $+85^{\circ}$ C.

For the types which can be used up to 125° C, the voltage must be derated between $+85^{\circ}$ C and $+125^{\circ}$ C according to the following curve.



For the types which can be used up to 200° C, the voltage must be derated between +85°C and +200°C according to the following curve.



The category voltage (U_c) is consequently the maximum DC voltage which can be applied continuously at +125°C.

The surge voltage is the maximum voltage which can be applied for short periods.

It is given for each type in the data sheet and is generally equal to 1,15 times U_R between -55° C and $+85^{\circ}$ C and 1,15 times U_C at $+125^{\circ}$ C.

Tests are performed with charging periods of 30 seconds, through a 1000 Ω resistor, and discharging periods of 5 min 30s. 1000 cycles are done.

REVERSE VOLTAGE

Capacitors in silver cases (CT4, CT4E, CT9, CT9E) and some in tantalum cases (WT83, WS83) cannot withstand any reverse voltage: it would cause damage, more or less rapidly depending upon the voltage value.

It is therefore necessary to be sure that the bias voltage is high enough to avoid that the AC voltage creates a reverse voltage (negative peak).

Other capacitors in tantalum cases (CT79, CT79E, ST79, DSCC 93026, M39006/22 and M39006/25) can withstand a reverse voltage as specified in the individual datasheet.

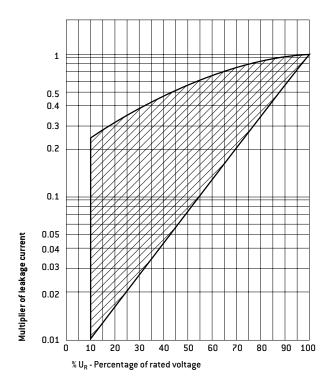
LEAKAGE CURRENT

Leakage current is the residual current which flows through the capacitor after the charging time, under rated voltage. It is measured after a time not exceeding 5 minutes and is given in μ A.

It is equivalent to the insulation resistance of the capacitor and it must be as low as possible.

Maximum leakage current is a function of capacitance and rated voltage values and is given, for each type, in the data sheets.

LEAKAGE CURRENT CHANGE VS APPLIED VOLTAGE





DISSIPATION FACTOR

Dissipation factor is generally measured at the same time as the capacitance, with the same conditions. It is a function of the series resistance of the capacitor and the capacitance at low frequency.

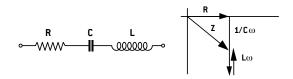
DF = ESR x C x 2 π f

At low frequency, the series resistance is the sum of an ohmic part (leads, contacts, MnO_2) and the dielectric losses.

Dissipation factor is given in % and maximum limits are given for each type in the data sheets.

EQUIVALENT SERIES RESISTANCE OR IMPEDANCE

Equivalent circuit of a capacitor



- R: equivalent series resistance of the capacitor (leads,contacts, MnO_2 , dielectric losses)
- L: inductance mainly due to the leads
- C: capacitance

Impedance

It is specified at 100Hz and -55°C and the formula for impedance is:

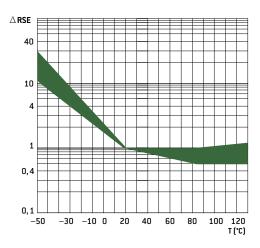
$$Z = \sqrt{R^2 + (L\omega - 1/C\omega)^2}$$

It can be seen that:

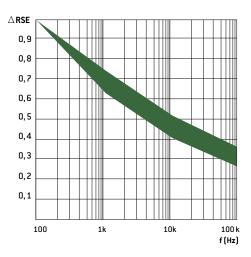
- at low frequencies, impedance is a function of capacitance
- at high frequencies, impedance is a function of inductance
- at medium frequencies, it is a function of the ESR

Maximum impedance: see data sheets.

ESR CHANGE VS TEMPERATURE



ESR CHANGE VS FREQUENCY



HERMETICALLY SEALED - TANTALUM CASES WET TANTALUM CASES

Electrical characteristics

MAXIMUM RIPPLE CURRENT

CT79/79E (SMD) - CT79/79E HT200 - ST79 (SMD) - ST79 HT200 - WT83 - WS83

Maximum ripple currents which are indicated in the data sheets are given for the following conditions:

Temperature: +85°C (+70°C only WT82)

Frequency: 40kHz Applied voltage: 0,66

If conditions are different, use the multipliers given in the table below to calculate the new maximum current.

Frequency 100Hz				1k	Hz		10kHz				40kHz				100kHz						
Temperatu	Temperature +55°C +85°C +105°C		+105°C	+125°C	+55°C	+85°C	+105°C	+125°C	+55℃	+85°C	+105°C	+125°C	+55℃	+85°C	+105°C	+125°C	+55℃	+85°C	+105°C	+125°C	
	66%	0,6	0,6	0,46	0,27	0,72	0,72	0,55	0,32	0,88	0,88	0,68	0,4	1	1	0,77	0,45	1,1	1,1	0,85	0,5
	70%	0,6	0,58	0,44	-	0,72	0,7	0,52	-	0,88	0,85	0,64	-	1	0,97	0,73	-	1,1	1,07	0,8	-
Peak voltage in % of U _P	80%	0,6	0,52	0,35	-	0,72	0,62	0,42	-	0,88	0,76	0,52	_	1	0,87	0,59	-	1,1	0,96	0,65	-
III % OI OR	90%	0,6	0,46	-	-	0,72	0,55	-	-	0,88	0,67	-	_	1	0,77	-	-	1,1	0,85	-	_
	100%	0,6	0,39	_	_	0,72	0,45	-	-	0,88	0,55	-	_	1	0,63	_	-	1,1	0,69	_	_

CT4 - CT4E - CT9 - CT9E TYPES

Maximum ripple currents which are indicated in the data sheets are given for the following conditions:

- frequency from 100Hz to 100kHz and more
- temperature from -55° C to $+85^{\circ}$ C

Correction vs temperature

If the temperature is higher than 85°C, decrease linearly the maximum value from 100% at +85°C to 80% at +125°C.

Correction vs frequency

If frequency is lower than 100Hz, apply the following multipliers to the maximum ripple currents:

75Hz: 0,79 **60Hz:** 0,65 **50Hz:** 0,55 **25Hz:** 0,55

OTHERS RULES (FOR ALL TYPES)

- the sum of the positive peak AC voltage and the DC bias voltage must be lower than the rated voltage.
- the negative peak must not create any Reverse voltage (or maximum 3 volts for CT79 and CT79E types).
- because of the increase of the series resistance at low temperature, it is better to not apply directly the maximum ripple current but to increase this one gradually to raise the capacitor temperature.

CLIMATIC CHARACTERISTICS

1- CLIMATIC CATEGORY

Climatic category defines the temperature range over which the capacitor can be used continuously, and also the number of days for the damp heat test [this test is performed periodically at 40°C with a 93% moisture rate].

Note: it is necessary to derate the voltage for temperatures higher than 85° C (see page 15).

2- THERMAL SHOCKS - RAPID CHANGES OF TEMPERATURE

This test is performed to check that the capacitors can withstand sudden temperature changes. The method which is used is the one with two chambers, one at -55° C, the other one at $+125^{\circ}$ C. Five cycles are performed, with 30min at low temperature and 30min at high temperature, during the periodical tests (30 cycles for CT79 type). Electrical characteristics are measured after this test.

3 - DAMP HEAT TEST

This test is performed during the periodical test, with the following conditions:

Temperature: 40°C Humidity: 90 to 95% DC voltage: without Time: 21 or 56 days

Electrical characteristics are measured after this test.

MECHANICAL CHARACTERISTICS

1 - VIBRATIONS

This test is performed during the periodical test, with the following conditions:

CT9 - CT9E types

• Frequency: 10 to 2000Hz

• Amplitude: 1,5mm or 196m/s2 - 20g

• Time: 6 hours

CT79/79E (SMD) - CT79/79E HT200 - ST79 (SMD) - ST79 HT200 - WT83 - WS83

• Frequency: 10 to 2000Hz

• Amplitude: 3,5mm or 490m/s2 - 50g

• Time: 6 hours

2 - SHOCKS

This test is performed just after the vibrations test, with the following conditions for all types:

- Acceleration: 981 m/s² 100g
- Pulse width: 6 ms
- Shape: 1/2 sinewave
- Number of shocks: 18 (3 in each direction, positive and negative)



RELIABILITY

Reliability of a component can be defined as its probability to work without any failure, in defined conditions and during a fixed time.

Reliability is not therefore only a function of the component quality, but also of the application and environmental conditions.

The parameter which is the most commonly used for the reliability is the failure rate in time, generally expressed in % per 1000 hours.

CALCULATION OF A COMPONENT FAILURE RATE USED IN AN EQUIPMENT

The calculation method on the next page uses parmeters which are given by the CNET (Centre National d'Étude des Télécommunications) in its Reliability Data Book (RDF 1993).

The failure rate is calculated with parameters which are function of the capacitor (capacitance, case type, approvals, high surge current test) and others ones which are representative of application conditions (voltage, temperature, resistance in serie, environmental conditions).

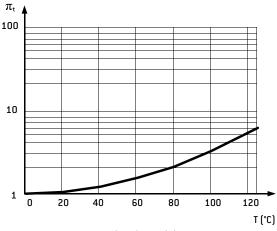
Example:

CT79E 2200 μ F - 6,3 V used under 3 volts, at 40°C, in a satellite in orbit:

$$\pi_{t} = 1.2 \ \pi_{V} = 1.38 \ \pi_{C} = 1.4 \ \pi_{E} = 0.5 \ \pi_{G} = 1$$

 $\lambda = 3 \times 1,2 \times 1,38 \times 1,4 \times 0,5 \times 1.10^{-9}/h = 3,5.10^{-9}/h = 0,00035 \%$ defects/1000 hours

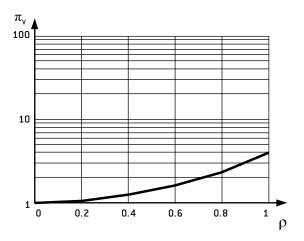
π_{\star} = TEMPERATURE INFLUENCE



Formula: $\pi_t = \exp(1,8.(t/tm)^2)$ with: t = using temperaturetm = maximum temperature

tm = maximum tempera Curve for tm = 125° C

π_{v} = influence of applied voltage vs rated voltage



Formula: $\pi_{v} = \exp((\rho / 0.85)^{2})$

$$\rho = \frac{\text{peak voltage}}{\text{rated voltage}}$$

Curve $\pi_v = f(\rho)$

π_c = influence of capacitance

3,3 <i>µ</i> F	$oldsymbol{\pi}_{ extsf{c}}$ = 0,9
20μF	$oldsymbol{\pi}_{ extsf{C}}$ = 1,0
1000μF	$oldsymbol{\pi}_{ extsf{C}}$ = 1,3
2200UE	$\pi_c = 1.4$

$\pi_{\rm E}$ = influence of application

Satellite in orbit	$oldsymbol{\pi}_{\scriptscriptstyle extsf{E}}$ = 0,5
Ground; stationary; protected	$oldsymbol{\pi}_{E}$ = 1
Ground; stationary; non protected	$oldsymbol{\pi}_{E}$ = 2,5
Ground; mobile; soft conditions	$oldsymbol{\pi}_{\scriptscriptstyle{E}}$ = 6
Aircraft; soft conditions	$oldsymbol{\pi}_{\scriptscriptstyle E}$ = 6
Ship; soft conditions	$oldsymbol{\pi}_{\scriptscriptstyle{E}}$ = 6
Ground; mobile; hard conditions	$oldsymbol{\pi}_{\scriptscriptstyle E}$ = 8
Ship; hard conditions	$oldsymbol{\pi}_{ extsf{E}}$ = 10
Aircraft; hard conditions	$oldsymbol{\pi}_{\scriptscriptstyle extsf{E}}$ = 15
Satellite; launching	$oldsymbol{\pi}_{\scriptscriptstyle E}$ = 20

π_{a} = influence of qualification

Products approved to CECC	$oldsymbol{\pi}_{ extsf{q}}$ = 1,0
Others products	π_{α} = 2,0

PRODUCT SAFETY INFORMATION SHEET

This should read in conjunction with the Product Data Sheet/Specification.

Failure to observe the ratings, and the information on this sheet may result in a safety hazard.

1. MATERIAL CONTENT

Wet tantalum capacitors contain hazardous materials:

- Liquid electrolyte gelled diluted sulphuric acid
- Solid tantalum anode

The device consists of solder coated terminal wires and the materials listed below:

- Silver case or tantalum case
- Rubber "o" rings
- PTFE spacers
- Filled epoxy resin end cap on silver case products

2. PHYSICAL FORM

These Capacitors are physically small and are cylindrical with axial leads.

3. INTRINSIC PROPERTIES

3.1 Operating

Wet tantalum capacitors will operate satisfactorily providing that the sum of the applied d.c. and the peak a.c. ripple voltage does not exceed the rated d.c. voltage. There must be no reversal of polarity.

The maximum ripple currents and voltages and d.c. polarising voltages are specified in the data sheets.

Some tantalum cased devices will stand up to 3 V_{DC} Reverse for short periods of

A Reverse application of the rated voltage will result in loss of capacitance, early short circuit failure and may result in fire or explosion.

It may also cause consequential failure of other associated components in circuit, e.g. diodes, transformers, etc.

3.2 Non-Operating

Wet Tantalum capacitors contain electrolyte which is a conducting material.

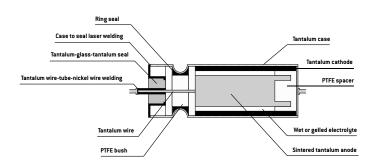
If electrolyte leaks onto a printed circuit board or similar insulated support, short circuits can be caused.

All electrolytes are corrosive to some extent.

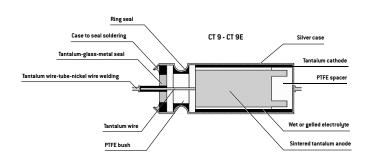
No electrolyte should be allowed to come in contact with the skin, eyes, etc., and if they do appropriate medical treatment should be applied.

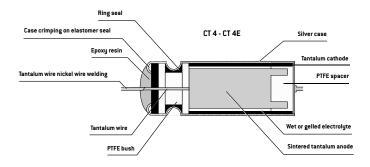
CONSTRUCTION

CT79/79E (SMD) - CT79/79E HT200 - ST79 (SMD) - ST79 HT200 - WT83 - WS83

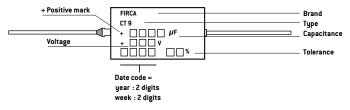


Glass metal seal: CT9 - CT9E Epoxy sealing: CT4 - CT4E





MARKING (except DSCC 93026, M39006/22, M39006/25)



PACKAGING

In cardboard boxes



General information

Tantalum capacitors are, with ceramic, aluminum and film capacitors, one of the most used family.

The manufacturing technology and the constant improvements in tantalum powders allow it to be the capacitor with the highest CV (product capacitance x voltage) per volume, very long life and high reliability.

It has also the following advantages:

- Wide range of capacitance (less than 1μ F to more than $10\,000\mu$ F)
- Wide operating temperature range (-55°C to +200°C)
- Electrical characteristics stable with temperature
- Low leakage current
- Very low ESR for some types
- · Stability after long periods of storage, without any reforming

All these characteristics allow tantalum capacitors to be commonly used either in large volume markets like mobile phones or computers, or in specific High-Rel applications such as space, aerospace and military.

Its main uses are found in the following functions:

Filtering

• RC time constant

• Bypass

Energy storage

Wet tantalum capacitors:

Tantalum cases

Silver cases

Coupling

Tantalum capacitors can be divided into two main families and several subfamilies:

Solid tantalum capacitors:

Solid Mn0₂

- Metal cases
- Molded cases
- SMD
- Solid Polymer
 - SMD

HOW TO USE THE SELECTION GUIDE

- 1 The **Technical Selection Guide** can be used to select a product according to the main technical requirements.
- 2 The Classification according to specification makes the link between all major standard specifications and the products.
- 3 The Selection Guide by family has the same classification as in the catalogue. You will find for each type the main features, the approvals and the page number of the technical data sheet.

MANUFACTURING

ANODE AND INSULATOR

Tantalum capacitors are the capacitors which have the highest ratio of capacitance per volume. This is mainly due to the high dielectric coefficient of its insulator and to its large cross-section.

The basic raw material is a high purity (greater than 99,99%) tantalum powder with a very fine granulation, compressed to form a cylinder or a parallelipiped constituting the anode of the capacitor (positive plate).

The pellet is then sintered at high temperature (1200° C to 2200° C), under high vacuum (10^{-6} Torr), firstly to purify the powder and secondly to obtain a strong mechanical structure by a welding of the particles.

The insulating part is obtained by anodization to a depth of the tantalum surface which forms a tantalum pentoxide film $\{Ta_20_5\}$ with a thickness of about 16 angstroms per anodization volt. The dielectric coefficient is between 21 and 27 depending upon the anodization conditions.

WET ELECTROLYTE: CATHODE AND ENCAPSULATION

In this case, the cathode is formed by a sulphuric acid solution. The anodized tantalum pellet is impregnated with this solution and then placed in a silver or tantalum case, into which some equivalent gelled solution have been previously deposited.

The case is then crimped on the internal PTFE gasket to make the sealing. The final steps are welding (CT79), soldering (CT9) or elastomer seal (CT4) depending on the capacitors.

SOLID ELECTROLYTE: CATHODE AND ENCAPSULATION

In this case, the cathode is formed either by managanous dioxide which is a grey semi conductor or by polymer solution.

Solid MnO_2 cathode is obtained by dipping the pellets into a manganous nitrate water solution which impregnates the internal structure; this solution is then decomposed in a high temperature oven to obtain manganous dioxide. This operation is repeated several times. The nature and quality of this semiconductor are important to some of the electrical parameters (especially the serial resistance).

To finish the negative plate, a graphite coating and then a silver coating are deposited on the outside surface of the manganous dioxide or conducting polymer.

The positive nickel lead is welded on the tantalum wire and the negative lead is either soldered for the products with axial leads or glued with a silver epoxy for the SMD range.

BURN-IN - SORTING - INSPECTION

All the products are submitted to a final burn-in, with differing severities depending upon the characteristics of each type (temperature, voltage, duration).

Then follows the sorting, marking and inspection operations. It can be noted that the procedures for these operations are the same for approved and non approved parts (except the periodical tests).



General information

TYPE IDENTIFICATION - ORDERING INFORMATION

THE COMPLETE IDENTIFICATION OF A PRODUCT IS MADE OF

- The type (or model)
- The tolerance
- The case size
- The rated voltage
- The rated capacitance
- If applicable the CECC specification number

THE TYPE

It can be expressed with the commercial description (CTC21E C 33μ F 10% 40V) or the **EXXELIA** part number (TS22EC336K040F).

When applicable the CECC specification number should be indicated.

THE CASE SIZE

It is indicated on the technical data sheets in front of each capacitance-voltage value and is generally identified by a letter code. It is important to give this information because there can be, for the same type, a standard range and an extended range in which the same value will be available in two different sizes.

THE RATED CAPACITANCE

It can be expressed:

- Directly in μ F (eg: 47 μ F)
- Coded according to MIL specification, with:
 - 2 digits number for the value
 - A multiplying factor to obtain the capacitance in pF (power of 10)

Eg: $567 = 56.10^7 \text{ pF} = 560 \mu\text{F}$

THE TOLERANCE

It can be expressed directly in % or identified by a code letter:

 $M = \pm 20\%$

 $K = \pm 10\%$

 $J = \pm 5\%$

N.B.: the standard tolerance for tantalum capacitors is 20%; if no tolerance is specified, it would be considered as 20%.

A 20% tolerance means in fact -20% to +20%.

THE RATED VOLTAGE

It is expressed directly in volts (V)

N.B.: 6,3V rated voltage can be coded as 6V.

CECC SPECIFICATIONS

Some of the products which are described in this catalogue are made to a CECC specification; these documents give in detail the following information for each type:

- The climatic, electrical and mechanical characteristics
- The test and inspection procedures
- The sampling methods and levels
- The tests periods

The reference specifications concerning the tantalum capacitors are the following:

CECC 30 000 (NFC 83-100)

Generic specification: fixed capacitors

- Terminology
- Quality Assessment Procedures
- Test and inspection methods

CECC 30 200 (NFC 83-112)

Sectional specification: tantalum capacitors

- Prefered characteristics
- Quality Assessment Procedures
- Test and inspection methods

CECC 30 201 XXX

Detail specifications solid tantalum capacitors

• Detailed characteristics for each type

CECC 30 202 XXX

Detail specifications wet tantalum capacitors

• Detailed characteristics for each type

CECC 30 800 (NFC 83-113)

Sectional specification: tantalum chip capacitors

- Prefered characteristics
- Quality Assessment Procedures
- Test and inspection methods

CECC 30 801 XXX

Detail specifications tantalum chip capacitors

- Detailed characteristics for each type
- The list of all the detail specifications is given in the selection guide, with the corresponding type.

NB: Some of the products refer to specifications which are no longer published.

OTHER SPECIFICATIONS

In addition to CECC approvals, some of the products are qualified to MIL standard M39006/22, M39006/25, DSCC DWG No. 93026 and some others are listed in ESA (European Space Agency) Preferred Parts Lists ESCC EPPL I or II.

